

## **Description**

The MCH3376 uses advanced trench technology

to provide excellent  $R_{\text{DS}(\text{ON})}$ , This device is suitable

for use as a load switch or in PWM applications.



SOT-323

 $V_{DS} = -20V, I_{D} = -1.8A$ 

**General Features** 

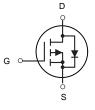
 $R_{DS(ON)}$  < 150m $\Omega$  @  $V_{GS}$ =-4.5V

## **Application**

Battery protection

Load switch

Uninterruptible power supply



P-Channel MOSFET

### **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
MCH3376	SOT-323	HXY MOSFET	3000

## Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

Symbol	Parameter	Limit	Unit
V <sub>DS</sub>	Drain-Source Voltage	-20	V
Vgs	Gate-Source Voltage	±8	V
ID	Drain Current-Continuous	-1.8	А
Ірм	Drain Current-Pulsed (Note 1)	-3	А
P <sub>D</sub>	Maximum Power Dissipation	0.29	W
ТЈ,Тѕтс	Operating Junction and Storage Temperature Range	-55 To 150	°C
Rеја	Thermal Resistance,Junction-to-Ambient (Note 2)	431	°C/W



# Electrical Characteristics (TA=25 $^{\circ}$ C unless otherwise noted)

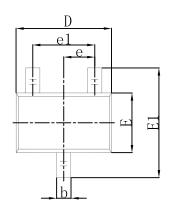
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
STATIC CHARACTERISTICE							
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =-250μA	-20			V	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =-18V,V <sub>GS</sub> = 0V			-1	μA	
Gate-body leakage current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V, V <sub>DS</sub> = 0V			±100	nA	
Gate threshold voltage (note2)	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-0.4	-0.7	-1.0	V	
	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2A			150	mΩ	
Drain-source on-resistance (note2)		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.0A			230	mΩ	
Maximum Continuous Drain to Source Diode Forward Current	Is				-1.0	А	
Diode forward voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V			-1.2	V	
DYNAMIC CHARACTERISTICS (note3)							
Input capacitance	C <sub>iss</sub>				680	pF	
Output capacitance	Coss	V <sub>DS</sub> =-8V,V <sub>GS</sub> =0V, f =1MHz			130	pF	
Reverse transfer capacitance	C <sub>rss</sub>	1 - 11/11/12			95	pF	
SWITCHING CHARACTERISTICS (note3)							
Turn-on delay time	t <sub>d(on)</sub>				10	nS	
Turn-on rise time	t <sub>r</sub>	V <sub>GS</sub> =-4.5V,V <sub>DS</sub> =-10V,			20	nS	
Turn-off delay time	t <sub>d(off)</sub>	$I_D$ =-1.0A, $R_G$ =5.1 $\Omega$			35	nS	
Turn-off fall time	t <sub>f</sub>				18	nS	

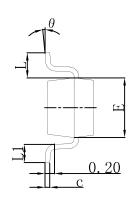
#### Notes:

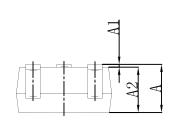
- 1. Surface mounted on FR4 board using the minimum recommended pad size.
- 2. Pulse Test: Pulse Width=300µs, Duty Cycle=2%.
- 3. These parameters have no way to verify.



# **SOT-323 Package Outline Dimensions**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650	TYP	0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
K	0°	8°	0°	8°	



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